74HC74; 74HCT74

Dual D-type flip-flop with set and reset; positive edge-trigger

Rev. 4 — 27 August 2012

Product data sheet

1. General description

The 74HC74 and 74HC774 are dual positive edge triggered D-type flip-flop. They have individual data (nD), clock (nCP), set (n \overline{S} D) and reset (n \overline{R} D) inputs, and complementary nQ and n \overline{Q} outputs. Data at the nD-input, that meets the set-up and hold time requirements on the LOW-to-HIGH clock transition, is stored in the flip-flop and appears at the nQ output. Schmitt-trigger action in the clock input, makes the circuit highly tolerant to slower clock rise and fall times. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. Features and benefits

- Input levels:
 - ◆ For 74HC74: CMOS level
 - ◆ For 74HCT74: TTL level
- Symmetrical output impedance
- Low power dissipation
- High noise immunity
- Balanced propagation delays
- Specified in compliance with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

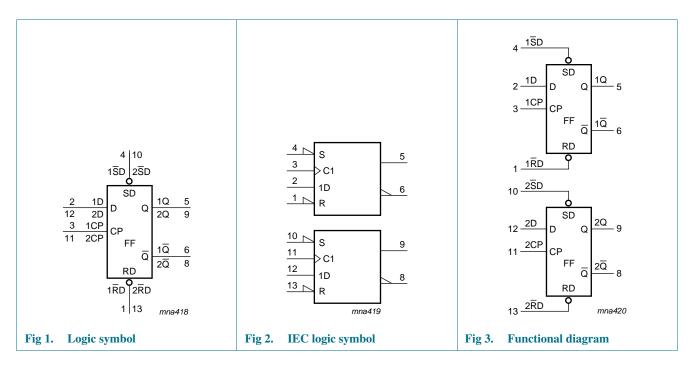
Type number	Package								
	Temperature range	Name	Description	Version					
74HC74N	–40 °C to +125 °C	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1					
74HCT74N									
74HC74D	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width	SOT108-1					
74HCT74D			3.9 mm						
74HC74DB	-40 °C to +125 °C	SSOP14	plastic shrink small outline package; 14 leads; body	SOT337-1					
74HCT74DB			width 5.3 mm						

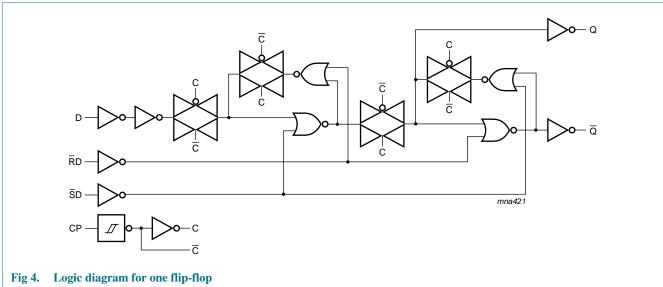


 Table 1.
 Ordering information ...continued

Type number	Package								
	Temperature range	Name	Description	Version					
74HC74PW	−40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads;	SOT402-1					
74HCT74PW			body width 4.4 mm						
74HC74BQ	−40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very	SOT762-1					
74HCT74BQ			thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm						

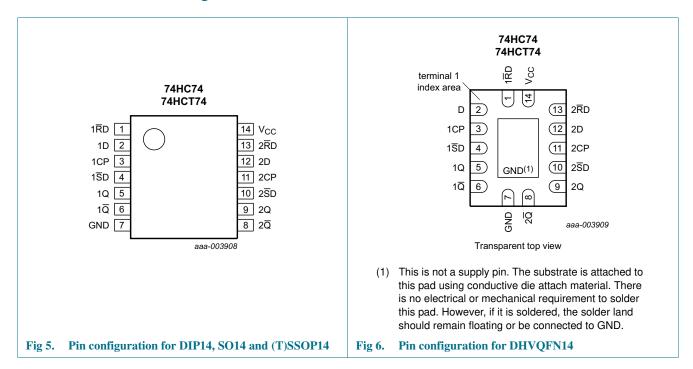
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Tubic 2.	i ili description	
Symbol	Pin	Description
1RD	1	asynchronous reset-direct input (active LOW)
1D	2	data input
1CP	3	clock input (LOW-to-HIGH, edge-triggered)
1SD	4	asynchronous set-direct input (active LOW)
1Q	5	output
1Q	6	complement output
GND	7	ground (0 V)
2Q	8	complement output
2Q	9	output
2SD	10	asynchronous set-direct input (active LOW)
2CP	11	clock input (LOW-to-HIGH, edge-triggered)
2D	12	data input
2RD	13	asynchronous reset-direct input (active LOW)
V_{CC}	14	supply voltage

6. Functional description

Table 3. Function table[1]

Input			Output		
nSD	nRD	nCP	nD	nQ	nQ
L	Н	X	X	Н	L
Н	L	Χ	Χ	L	Н
L	L	Χ	Χ	Н	Н

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

Table 4. Function table[1]

Input		Output			
nSD	nRD	nCP	nD	nQ _{n+1}	nQ _{n+1}
Н	Н	\uparrow	L	L	Н
Н	Н	\uparrow	Н	Н	L

^[1] H = HIGH voltage level; L = LOW voltage level; ↑ = LOW-to-HIGH transition; Q_{n+1} = state after the next LOW-to-HIGH CP transition; X = don't care.

7. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _O	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I _{CC}	supply current		-	+100	mA
I_{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	DIP14 package	<u>[1]</u> -	750	mW
		SO14, (T)SSOP14 and DHVQFN14 packages	[1] -	500	mW

^[1] For DIP14 package: P_{tot} derates linearly with 12 mW/K above 70 $^{\circ}\text{C}.$

For SO14 package: Ptot derates linearly with 8 mW/K above 70 °C.

For (T)SSOP14 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.

For DHVQFN14 packages: P_{tot} derates linearly with 4.5 mW/K above 60 $^{\circ}\text{C}.$

8. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC74		74HCT74			Unit	
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V_{CC}	0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 \text{ V}$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T _{amb} =	-40 °C to	+85 °C	T _{amb} = -40 °	C to +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
74HC74								'
V _{IH}	HIGH-level	$V_{CC} = 2.0 \text{ V}$	1.5	1.2	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 \text{ V}$	3.15	2.4	-	3.15	-	V
		$V_{CC} = 6.0 \text{ V}$	4.2	3.2	-	4.2	-	V
V _{IL}	LOW-level	$V_{CC} = 2.0 \text{ V}$	-	0.8	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 \text{ V}$	-	2.1	1.35	-	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	2.8	1.8	-	1.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		$I_O = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	4.32	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	5.81	-	5.2	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	40	-	80	μΑ
Cı	input capacitance			3.5				pF
74HCT7	4							
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	2.0	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	8.0	-	8.0	V

 Table 7.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T _{amb} =	-40 °C to	+85 °C	$T_{amb} = -40$	°C to +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V_{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$		'		'	'	
	output voltage	$I_O = -4 \text{ mA}$	3.84	4.32	-	3.7	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$						
	output voltage	$I_O = 4.0 \text{ mA}$	-	0.15	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	-	±1.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	40	-	80	μА
Δl _{CC}	additional supply current	$\begin{split} &V_{I} = V_{CC} - 2.1 \text{ V;} \\ &\text{other inputs at } V_{CC} \text{ or GND;} \\ &V_{CC} = 4.5 \text{ V to } 5.5 \text{ V;} \\ &I_{O} = 0 \text{ A} \end{split}$						
		per input pin; nD, nRD inputs	-	70	315	-	343	μА
		per input pin; nSD, nCP input	-	80	360	-	392	μΑ
C _I	input capacitance			3.5				pF

^[1] All typical values are measured at T_{amb} = 25 °C.

10. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit see Figure 9.

Symbol	Parameter	Conditions		T _{amb} :	= –40 °C to	+85 °C	T _{amb} = -40	°C to +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
74HC74			'		1		'	1	
t _{pd}	propagation delay	nCP to nQ, n \overline{Q} ; see Figure 7	[2]						
		$V_{CC} = 2.0 \text{ V}$		-	47	220	-	265	ns
		$V_{CC} = 4.5 \text{ V}$		-	17	44	-	53	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	14	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	14	37	-	45	ns
		$\overline{\text{NSD}}$ to $\overline{\text{nQ}}$, $\overline{\text{NQ}}$; see Figure 8	[2]						
		$V_{CC} = 2.0 \text{ V}$		-	50	250	-	300	ns
		$V_{CC} = 4.5 \text{ V}$		-	18	50	-	60	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	15	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	14	43	-	51	ns
		$\overline{\text{NRD}}$ to $\overline{\text{nQ}}$; see Figure 8	[2]						
		$V_{CC} = 2.0 \text{ V}$		-	52	250	-	300	ns
		$V_{CC} = 4.5 \text{ V}$		-	19	50	-	60	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	16	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	15	43	-	51	ns
t _t	transition	nQ, nQ; see Figure 7	[3]						
	time	$V_{CC} = 2.0 \text{ V}$		-	19	95	-	110	ns
		$V_{CC} = 4.5 \text{ V}$		-	7	19	-	22	ns
		$V_{CC} = 6.0 \text{ V}$		-	6	16	-	19	ns
t _W	pulse width	nCP HIGH or LOW; see Figure 7							
		$V_{CC} = 2.0 \text{ V}$		100	19	-	120	-	ns
		$V_{CC} = 4.5 \text{ V}$		20	7	-	24	-	ns
		$V_{CC} = 6.0 \text{ V}$		17	6	-	20	-	ns
		nSD, nRD LOW; see <u>Figure 8</u>							
		$V_{CC} = 2.0 \text{ V}$		100	19	-	120	-	ns
		$V_{CC} = 4.5 \text{ V}$		20	7	-	24	-	ns
		$V_{CC} = 6.0 \text{ V}$		17	6	-	20	-	ns
t _{rec}	recovery	nSD, nRD; see Figure 8							
	time	$V_{CC} = 2.0 \text{ V}$		40	3	-	45	-	ns
		$V_{CC} = 4.5 \text{ V}$		8	1	-	9	-	ns
		$V_{CC} = 6.0 \text{ V}$		7	1	-	8	-	ns

7 of 21

Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit see Figure 9.

Symbol	Parameter	Conditions		T _{amb}	= –40 °C to	+85 °C	$T_{amb} = -40$	°C to +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _{su}	set-up time	nD to nCP; see Figure 7	'		'		1		'
		$V_{CC} = 2.0 \text{ V}$		75	6	-	90	-	ns
		$V_{CC} = 4.5 \text{ V}$		15	2	-	18	-	ns
		$V_{CC} = 6.0 \text{ V}$		13	2	-	15	-	ns
t _h	hold time	nD to nCP; see Figure 7							
		$V_{CC} = 2.0 \text{ V}$		3	-6	-	3	-	ns
		$V_{CC} = 4.5 \text{ V}$		3	-2	-	3	-	ns
		$V_{CC} = 6.0 \text{ V}$		3	-2	-	3	-	ns
f _{max}	maximum	nCP; see Figure 7							
	frequency	$V_{CC} = 2.0 \text{ V}$		4.8	23	-	4.0	-	MHz
		$V_{CC} = 4.5 \text{ V}$		24	69	-	20	-	MHz
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	76	-	-	-	MHz
		$V_{CC} = 6.0 \text{ V}$		28	82	-	24	-	MHz
C_{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; V_I = GND to V_{CC}	[4]	-	24	-	-	-	pF
74HCT7									
t _{pd}	propagation delay	nCP to nQ, \overline{nQ} ; see Figure 7	[2]						
		$V_{CC} = 4.5 V$		-	18	44	-	53	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	15	-	-	-	ns
		$n\overline{S}D$ to nQ , $n\overline{Q}$; see Figure 8	[2]						
		$V_{CC} = 4.5 \text{ V}$		-	23	50	-	60	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	18	-	-	-	ns
		nRD to nQ, nQ; see Figure 8	[2]						
		$V_{CC} = 4.5 \text{ V}$		-	24	50	-	60	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	18	-	-	-	ns
t _t	transition	nQ, nQ; see Figure 7	[3]						
	time	V _{CC} = 4.5 V		-	7	19	-	22	ns
t _W	pulse width	nCP HIGH or LOW; see Figure 7							
		$V_{CC} = 4.5 \text{ V}$		23	9	-	27	-	ns
		nSD, nRD LOW; see Figure 8							
		V _{CC} = 4.5 V		20	9	-	24	-	ns
t _{rec}	recovery	nSD, nRD; see Figure 8							
.00	time	V _{CC} = 4.5 V		8	1	-	9	-	ns
t _{su}	set-up time	nD to nCP; see Figure 7							
Ju		V _{CC} = 4.5 V							

Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit see Figure 9.

Symbol	Parameter	Conditions		T _{amb} :	= –40 °C to	+85 °C	T _{amb} = -40	Unit	
				Min	Typ[1]	Max	Min	Max	
t _h	hold time	nD to nCP; see Figure 7							
•		$V_{CC} = 4.5 \text{ V}$		3	-3	-	3	-	ns
max	maximum frequency	nCP; see Figure 7							
		V _{CC} = 4.5 V		22	54	-	18	-	MHz
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	59	-	-	-	MHz
C _{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; V_I = GND to V_{CC} - 1.5 V	[4]	-	29	-	-	-	pF

- [1] All typical values are measured at T_{amb} = 25 °C.
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [3] t_t is the same as t_{THL} and t_{TLH} .
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum (C_L \times V_{CC}{}^2 \times f_o)$$
 where:

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

11. Waveforms

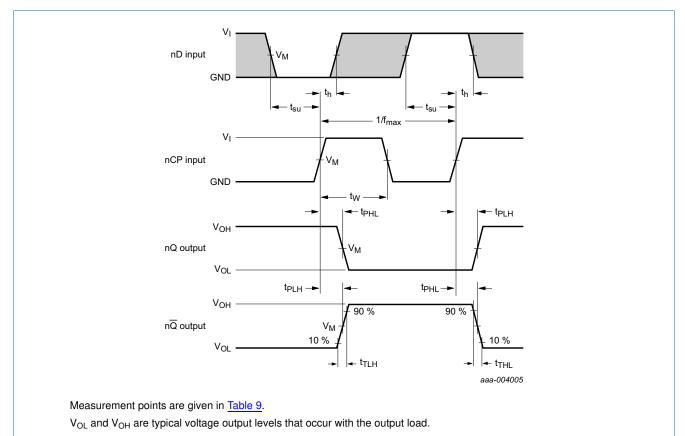


Fig 7. Input to output propagation delay, output transition time, clock input pulse width and maximum frequency

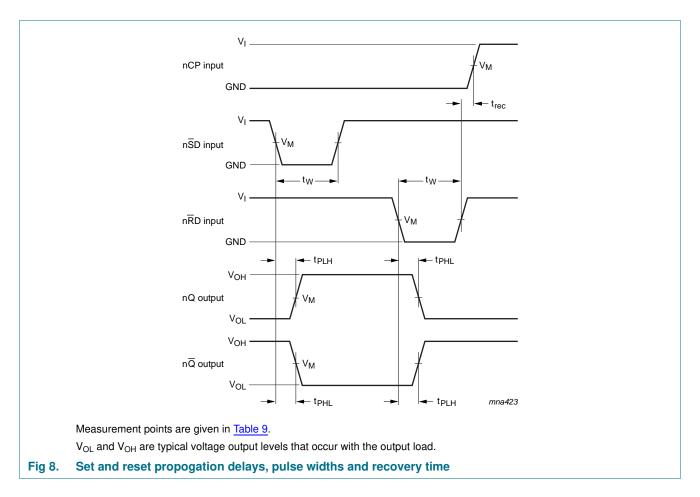
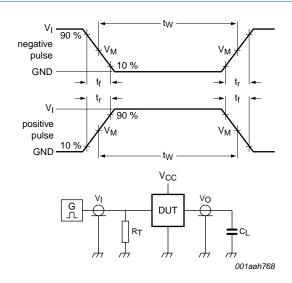


Table 9. Measurement points

Туре	Input	Output
	V _M	V _M
74HC74	0.5V _{CC}	0.5V _{CC}
74HCT74	1.3 V	1.3 V



Test data is given in Table 10.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

Fig 9. Test circuit for measuring switching times

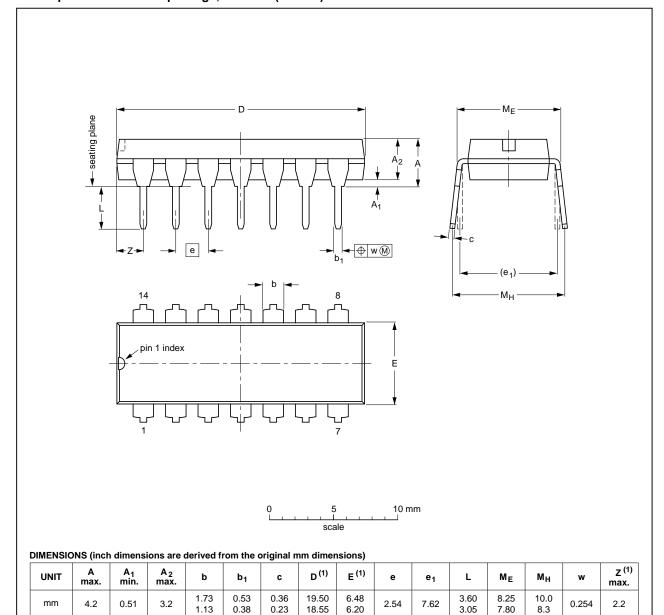
Table 10. Test data

Туре	Input		Load		Test
	VI	t _r , t _f	CL	RL	
74HC74	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	t _{PLH} , t _{PHL}
74HCT74	3 V	6 ns	15 pF, 50 pF	1 kΩ	t _{PLH} , t _{PHL}

12. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



inches

0.17

0.02

0.13

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

0.068

0.044

0.021

0.014

0.009

0.77

0.26

0.14

0.3

0.32

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT27-1	050G04	MO-001	SC-501-14		99-12-27 03-02-13

Fig 10. Package outline SOT27-1 (DIP14)

74HC_HCT74

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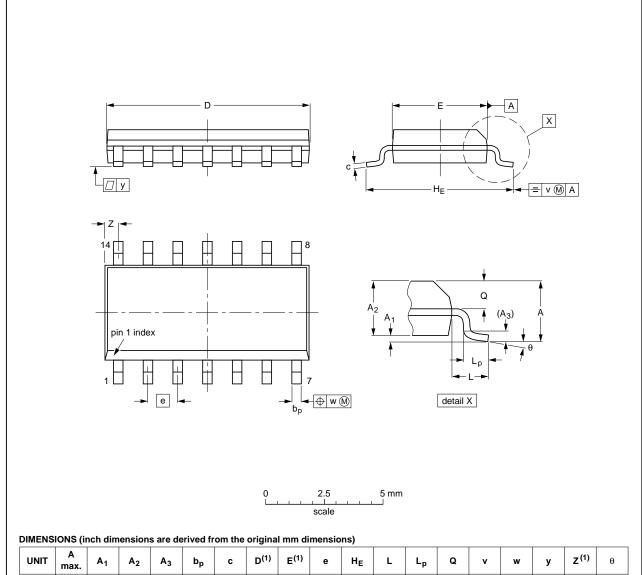
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0.01

0.087

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01	1	0.0100 0.0075	0.35 0.34	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012			99-12-27 03-02-19

Fig 11. Package outline SOT108-1 (SO14)

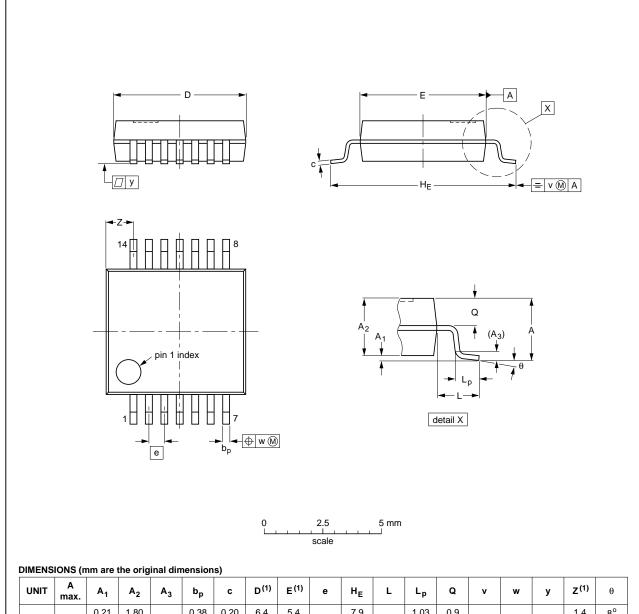
74HC_HCT74

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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



	•																	
UNIT	A max.	A ₁	A ₂	A ₃	b _p	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT337-1		MO-150			-99-12-27 03-02-19

Fig 12. Package outline SOT337-1 (SSOP14)

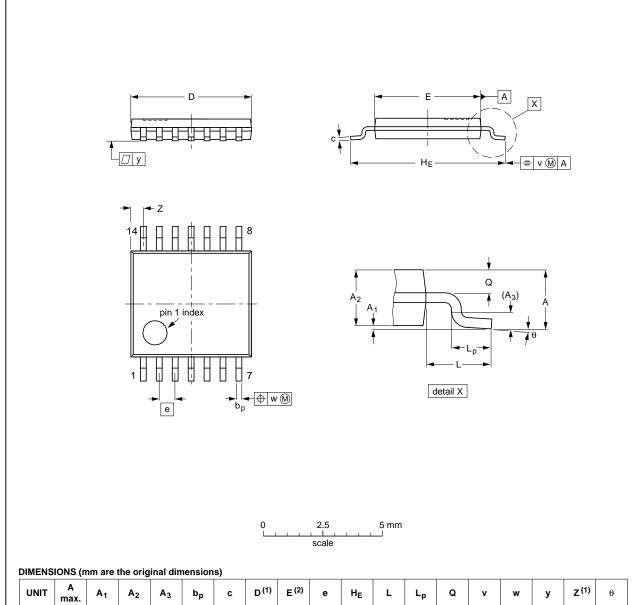
74HC_HCT74

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



						٠,												
UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

VERSION IEC JEDEC JEITA PROJECTION SOLUTION SOLU	OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
SO(402-1) $MO-153$ $++H+H+$	VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
03-02	SOT402-1		MO-153			99-12-27 03-02-18

Fig 13. Package outline SOT402-1 (TSSOP14)

74HC_HCT74

DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

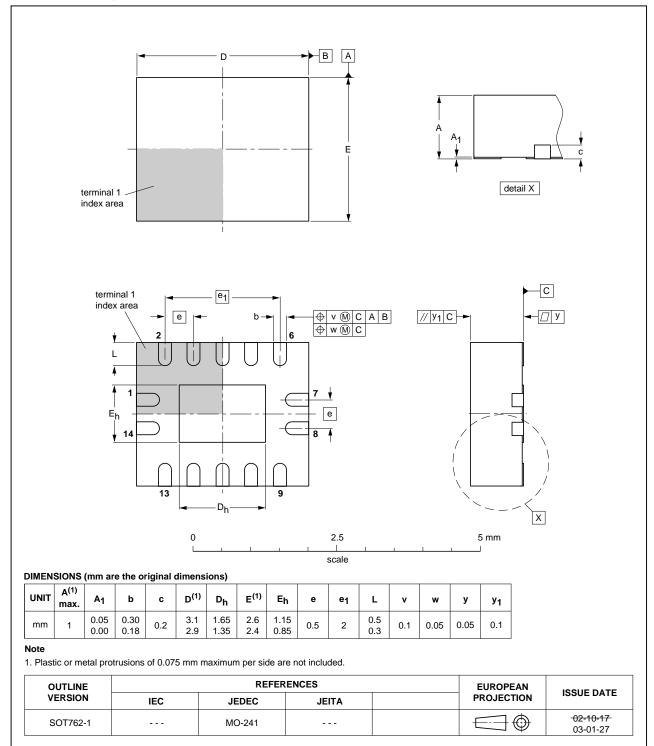


Fig 14. Package outline SOT762-1 (DHVQFN14)

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13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT74 v.4	20120827	Product data sheet	-	74HC_HCT74 v.3
Modifications:	guidelines	t of this data sheet has be of NXP Semiconductors. s have been adapted to th	· ·	
74HC_HCT74 v.3	20030710	Product data sheet	-	74HC_HCT74_CNV v.2
74HC_HCT74_CNV v.2	19980223	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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74HC_HCT74

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17. Contents

General description
Features and benefits
Ordering information 1
Functional diagram 2
Pinning information 3
Pinning
Pin description
Functional description 4
Limiting values 4
Recommended operating conditions 5
Static characteristics 5
Dynamic characteristics
Waveforms
Package outline
Abbreviations
Revision history 18
Legal information
Data sheet status
Definitions
Disclaimers
Trademarks20
Contact information 20
Contents

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